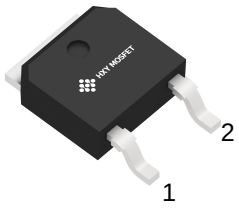
STPSC2H12B2Y-TR

Silicon Carbide Schottky Diode

Features

- 1200-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F



TO-252N-2L

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives

Part Number	Package	Qty(PCS)
STPSC2H12B2Y-TR	TO-252N-2L	2500

Maximum Ratings (T_C = 25 ˚C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V	
V_{RSM}	Surge Peak Reverse Voltage	1200	V	
I_F	Continuous Forward Current	9 4.3 2	A	T_C=25˚C T_C=135˚C T_C=164˚C
I_{FRM}	Repetitive Peak Forward Surge Current	10	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
I_{FSM}	Non-Repetitive Peak Forward Surge Current	30	A	T_C=25˚C, t_p = 10 ms, Half Sine Wave
P_{tot}	Power Dissipation	48 21	W	T_C=25˚C T_C=110˚C
T_J , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	˚C	
$\int i^2dt$	i²dt value	4.5	A^2s	T_C=25˚C, t_p = 10 ms, Half Sine Wave

Electrical Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Conditions
V_{DC}	DC Blocking Voltage	1200			V	
V_F	Forward Voltage		1.36 1.78	1.7 2.5	V	I_F = 2 A T_J=25°C I_F = 2 A T_J=175°C
I_R	Reverse Current		1.2 7.6	50 100	μA	V_R = 1200 V T_J=25°C V_R = 1200 V T_J=175°C
Q_C	Total Capacitive Charge		12		nC	V_R = 800 V T_J = 25°C
C	Total Capacitance		177 12 10		pF	V_R = 0 V, T_J = 25°C, f = 1 MHz V_R = 400 V, T_J = 25°C, f = 1 MHz V_R = 800 V, T_J = 25°C, f = 1 MHz
E_C	Capacitance Stored Energy		6		μJ	V_R = 800 V

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	3.1	°C/W

Typical Performance

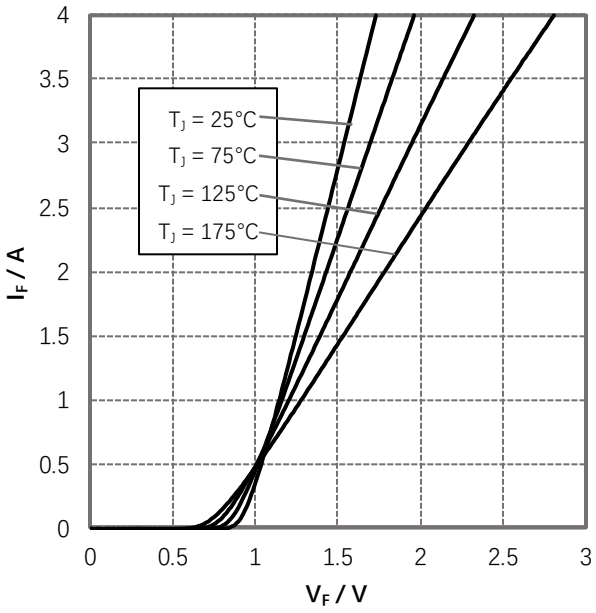


Figure 1. Forward Characteristics

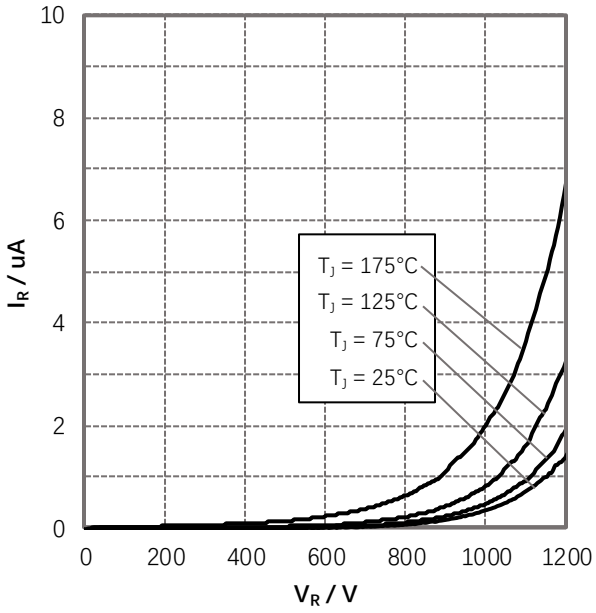


Figure 2. Reverse Characteristics

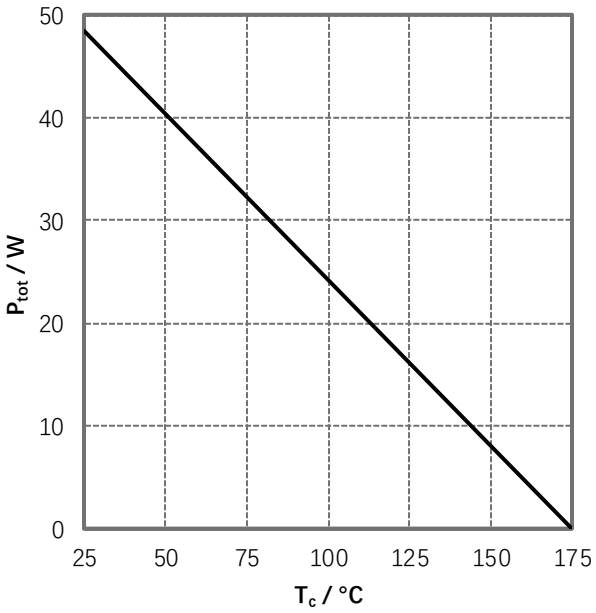


Figure 3. Power Derating

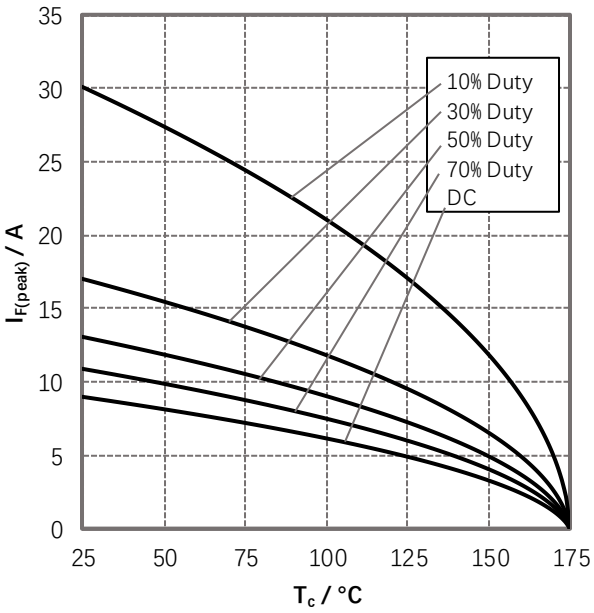


Figure 4. Current Derating

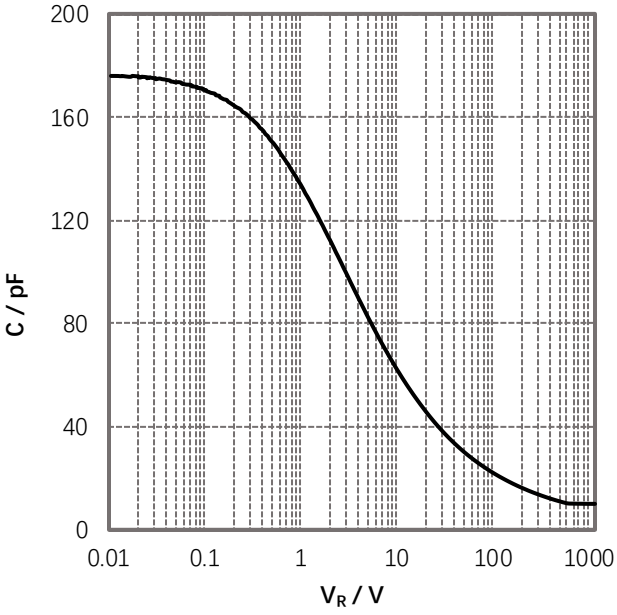


Figure 5. Capacitance vs. Reverse Voltage

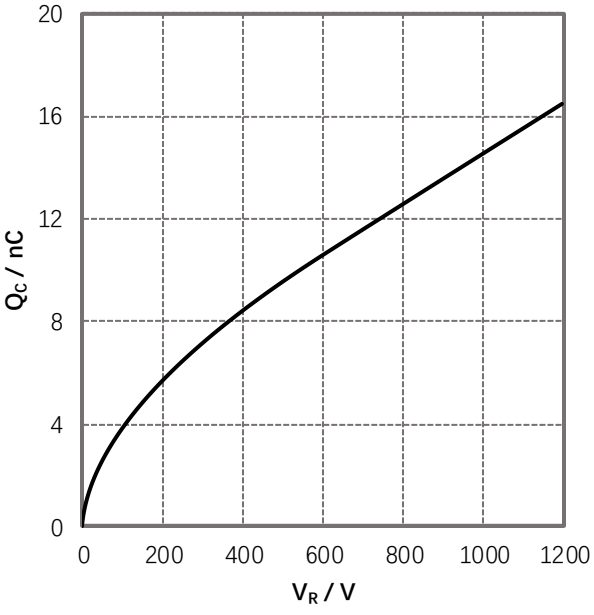


Figure 6. Total Capacitance Charge vs. Reverse Voltage

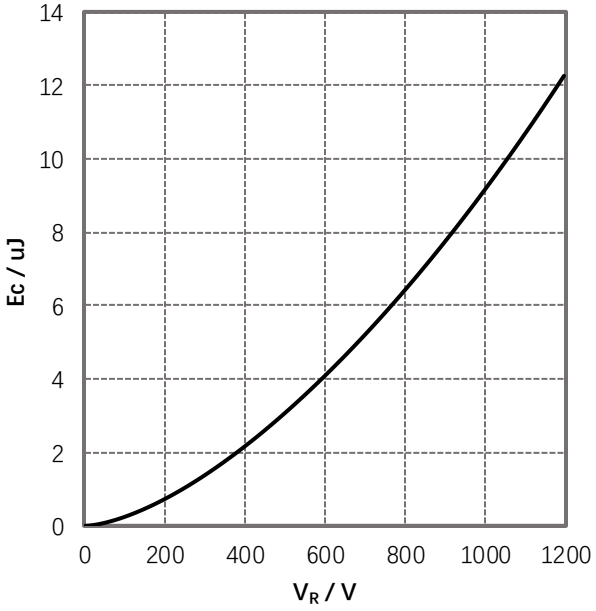


Figure 7. Capacitance Stored Energy

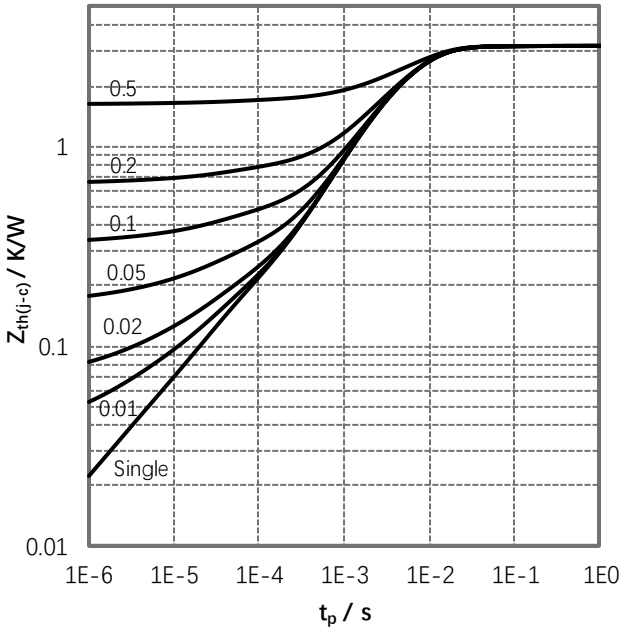
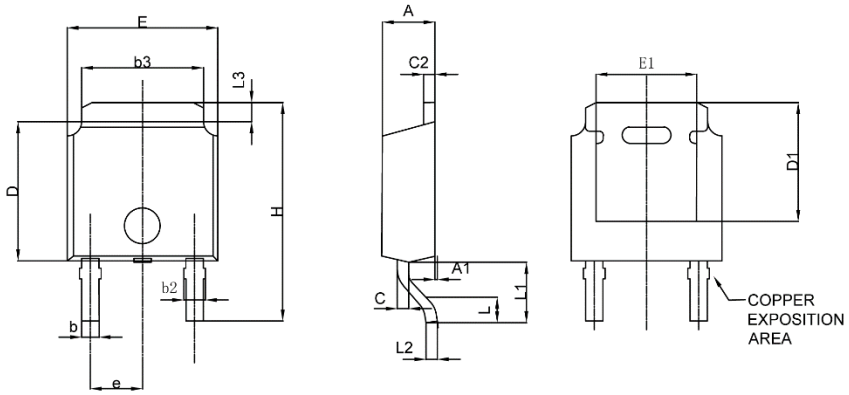


Figure 8. Transient Thermal Impedance

Package Information
TO-252N-2L



Symbol	DIMENSIONAL REQMTS		
	Min	Nom	Max
E	6.35	6.60	6.73
L	1.40	1.52	1.78
L1	2.743REF		
L2	0.508BSC		
L3	0.89	——	1.27
D	5.97	6.10	6.22
H	9.40	10.00	10.40
b	0.64	0.76	0.89
b2	0.76	0.84	1.14
b3	4.95	5.34	5.46
e	2.286BSC		
A	2.18	2.30	2.39
A1	0.00	——	0.13
c	0.46	0.50	0.61
c2	0.46	0.50	0.60
D1	5.21	——	——
E1	4.32	——	——

Note:
1.All Dimension Are In mm
2.Package Body Sizes Exclude Mold Flash,Protrusion Or Gate Burrs.
Mold Flash,Protrusion Or Gate Burrs Shall Not Exceed 0.10mm Per Side.
3.Package Body Sizes Determined At The Outermost Extremes
Of The Plastic Body Exclusive Of Mold Flash,
Gate Burrs And Interlead Flash,
But Including Any Mismatch Between
The Top And Bottom Of The Plastic Body.
4.The Package Top May Be Smaller Than The Package Bottom.
5.Dimension "b" Does Not Include Dambar Protrusion.
Allowable Dambar Protrusion Shall Be 0.10mm
Total In Excess Of "b" Dimension At Maximun Material Condition.
The Dambar Cannot Be Located On The Lower Radius Of The Foot.

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HXY MOSFET:

AQ15C-01FTG HAZ4007-01H LM393DR-HXY HSG3D15B3.3MA PESDSC2FD5VU PJEC5V0M1FN2
60N06 HSEN2411D3 HSTS521050B331 HRCLAMP3371ZCTFT HACPDQC5V0-HF PESDNC2XD5VBF
PJSD24CW_R1 AZ4836-01L ESD5L5.0C-HXY HESDSLC3V3D3B HLY323BC1524L HSEN3611D3
AZ4007-01H HCEZ36V,L3F HESD36VD3B HPTVSUC3D5VB PESDLC2FD3V3BH TPSMB28A-VR
BV05C-H ESD5LM5.0C-HXY HSD15C.TCT PESDNC2XD5VBL RLSD32A121V TPSMB100CA-VR